# Slave-boson approach to the in nite-U Anderson-Holstein impurity model

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The in nite-U Anderson-Holstein in purity model is studied with a focus on the interplay between the strong electron correlation and the weak electron-phonon interaction. The slave boson method has been employed in combination with the large degeneracy expansion (1=N) technique. The charge and spin susceptibilities and the phonon propagator are obtained in the approximation scheme where the saddle point conguration and the Gaussian 1=N uctuations are taken into account. The spin susceptibility is found not to be renormalized by electron-phonon interaction, while the charge susceptibility is renormalized. From the renormalized charge susceptibility the K ondo temperature is found to increase by the electron-phonon interaction. It turns out that the bosonic 1=N Gaussian uctuations play a very crucial role, in particular, for the phonon propagator.

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#### I. IN TRODUCTION

B oth electron correlation and lattice dynam ics are in portant in understanding the physical properties ofm any condensed m atter system s.<sup>1</sup> But the interplay between them has not been studied in detail because there are no reliable theoretical methods to describe the electronphonon interaction in the strongly correlated electron system s. For weakly correlated materials we have the successful Migdal Eliashberg theory.<sup>2</sup> There is, how ever, no system atic theoretical extension of the theory to the strongly interacting system s. W ith the recent advent of the dynam icalm ean eld theory (DMFT)<sup>3</sup> various lattice problem s can be mapped (or approxim ated) onto im purity problem s. In this context it is im portant to understand the correlated in purity problem coupled to local phonons.

One of the simplest model which incorporate both electron correlation and phonon is the Hubbard-Holstein (HH) model.<sup>4,5</sup> In the context of DMFT, it is mapped onto the Anderson-Holstein (AH) model.6,7 The AH model is a single-impurity Anderson model with a linear coupling to a local phonon mode as in the Holstein model.8 Recently, the HH model was studied with DMFT in combination with the num erical renorm alization group (NRG) at half- lling at zero tem perature<sup>4</sup>,9 The NRG method has also been successfully applied to AH  $m \text{ odel}^{6,7}$ , and  $a \ln ost exact results on the electron$ and phonon spectral functions have been obtained. How ever, it is still desirable to develop an analytic scheme in spite of its approxim ate nature since it helps us to understand the underlying physics in more clear and intuitive way. In this paper, we will consider the regime where the electron correlation dom inates over the phonon e ect, which will allow us to study the phonon e ects on the Kondo physics. The pure Holstein model without electron correlation is studied in Ref. 10 using sem iclassical

approximation and in Ref. 11 using NRG and DMFT.

W hen the local C oulom b repulsion of Anderson m odel is very large compared to the hybridization between the in purity and the conduction electrons, the in purity develops a magnetic moment at high tem perature regim e.<sup>5</sup> The moment is gradually screened by the spin of the conduction electrons as the tem perature is low ered below the K ondo tem perature scale. The physical properties of Anderson model at temperature lower than the Kondo tem perature can not be described within perturbative fram ework since the e ective K ondo coupling constant becom es very large in that tem perature regim e. This low tem perature state is often called the Kondo xed point in the sense of renormalization group  $.^{5,12}$  W e mention that the physics of K ondo xed point can describe the correlated m etallic states such as heavy ferm ions in the context of DMFT.

In the lim it of the in nite local Coulom b repulsion the impurity develops the local moment at high temperature and the system crosses over into the (completely screened) K ondo xed point at low tem perature. Thus the physical properties of the system in the lim it of innite local C oulom b repulsion are expected to be qualitatively sim ilar to those of other physical system s with very large but nite local Coulom b repulsion. If the local Coulomb repulsion is taken to be in nite the doubly occupied state of the impurity is not allowed in the physical Hilbert space. In general, the standard perturbative approach based on the W ick theorem on the electron operators and the associated Feynm an diagram expansions does not apply to the system s with the constrained Hilbert space. This fact poses a technical di culty for the approaches based on the electron operators. However, if we employ the slave eld representation of electron operators, the constrained Hilbert space can be treated in a considerably simplied way. The slave eld m ethod also adm its the Feynm an diagram expansion and

the direct manipulations of functional integrals. This slave eld method has been successfully applied to the in nite-U Anderson model<sup>3,14,15</sup> and it is particularly adequate in the study of the low temperature properties of the Anderson model. The bose condensed state which emerges in the saddle point (mean-eld) approximation embodies the K ondo resonant state, which is the crux of the K ondo xed point. Thus the essential physics of the K ondo xed point is captured in the leading approximation of the slave boson method. At high temperature the bose condensate disappears and it corresponds to the high temperature weak K ondo coupling regime where the perturbative approach such as the poor man's scaling<sup>16</sup> can be applied.

Our objective in this paper is to incorporate the phonon dynamics into the in nite-U Anderson model within the scheme of the slave boson method along the line pursued by Coleman.<sup>13</sup> W e will assume that the electron-phonon interaction is weak compared to the strong electron correlation, so that the physical situation at the zeroth approximation is still best described in terms of K ondo xed point physics. We have developed a scheme in which the electron-phonon interaction can be computed systematically in the large-degeneracy limit or, in other words, the 1=N expansion. The basic idea of the 1=N expansion is brie y illustrated in Appendix A.

The charge and spin susceptibilities of the impurity and the local phonon propagator have been obtained. Note that the dynam ical correlation functions are generally very hard to compute when the electron correlation is very strong. The feasibility of the analytic computation of the dynam ical correlation functions is the great advantage of the slave boson m ethods over other m ethods. It is found that the spin susceptibility of the im purity [Eq. (67)] is not modi ed by the electron-phonon interaction up to the approximation of Gaussian uctuations. The charge susceptibility of the impurity up to the second order in the (weak) electron-phonon coupling is given by Eq. (77). From the charge susceptibility at zero frequency, the K ondo tem perature renorm alized by the electron-phonon interaction can be extracted, and it is given by Eq. (81). Finally the phonon propagator is found to be Eq. (82). These are the main results of this paper. In all of these results the in uence of electron-phonon interaction is small since the charge

uctuations which directly couple to the local phonon are severely suppressed by very strong electron correlations. These results manifestly demonstrate the essential interplay between the strong electron correlation and the (weak) electron-phonon interaction. For instance, the sm all renorm alization by electron-phonon interaction in Eq. (81) is expressed by a product of the polaron energy and the K ondo energy, where the nonpeturbative physics of the electron correlation is encapsulated in the K ondo energy scale. The sm allness of the in uence of the electron-phonon interaction in our case is partially due to the absence of the orbital degrees of freedom. The electron 2

of phonons can be much more substantial for the materials with multi-orbitals, where the phonons can couple to the orbital quantum number.<sup>1</sup> Our approach can be extended to such cases, and the progresses in this direction are being made.

This paper is organized as follows. In Sec. II we introduce the AH m odel and the slave boson form alism. Then the rescaled e ective action in the Read-Newns gauge is obtained. In Sec. III we sum marize the basic results on the saddle point approximation by Coleman.<sup>13</sup> In Sec. IV the phonon dynamics is coupled to the bose excitation emerging in the 1=N expansion and the e ective action of them is computed. In Sec. V the spin and the charge susceptibilities are calculated from the e ective action obtained in Sec. IV and their physical properties are analyzed. In Sec. VI the phonon propagator is calculated from the e ective action obtained in Sec. IV. Sec. VII is for the sum mary and concluding remarks. Som e of details of the calculations can be found in the Appendices.

#### II. FORMALISM

#### A. Slave boson representation

The Ham iltonian of AH model consists of three parts.

$$H_{AH} = H_{el} + H_{ph} + H_{el ph}$$
(1)

H $_{\rm el}$  and H $_{\rm ph}$  is the H am iltonian for electron and phonon part, respectively, and H $_{\rm el}$  $_{\rm ph}$  is the H am iltonian describing the interaction between the electron and the phonon.

$$H_{el} = \begin{cases} X & X \\ k c_{k}^{y} c_{k} + f & f^{y} f + U f_{*}^{y} f_{*} f_{*}^{y} f_{*} \\ k; \\ + & \frac{X}{k} \frac{1}{N_{lat}} (V_{k} f^{y} c_{k} + V_{k} c_{k}^{y} f): \end{cases} (2)$$

$$H_{ph} = \frac{1}{2} M^{2}Q^{2} + \frac{P^{2}}{M}$$
 : (3)

$$\begin{array}{cccc} X & X \\ H_{el ph} = g_0 Q & f^y f & h & f^y f i : \end{array} \tag{4}$$

= ";# is the spin index, and  $V_k$  is the hybridization m atrix element. f is the impurity electron operator, and  $q_k$  is the conduction electron operator. f is the energy of the impurity level, and U is the local C oulom b repulsion at the impurity site. Q is local phonon coordinate. P is the conjugatem on entum of Q satisfying [Q;P] = i~. M is ion m ass and is the oscillator frequency of dispersionless (E instein) phonons. N <sub>lat</sub> is the num ber of lattice sites for the conduction electrons.  $g_0$  is the (unscaled) electron-phonon coupling constant. In the limit of in nite U, the doubly occupied state of impurity f electrons is prohibited. In this constrained H ilbert space, the impurity electron operator f can be expressed in terms of ferm ion operators and the slave boson operator b satisfying  $^{13,17}$ 

$$f^{Y} = s^{Y}_{X}b; f = s b^{Y};$$
 (5)

$$b^{y}b + s^{y}s = 1$$
: (6)

Now the remaining empty state and the singly occupied states denoted by spin quantum number at the impurity site can be represented as follows.

$$jem ptyi = b^{y} jefi;$$

$$j i = s^{y} jefi; \qquad (7)$$

where jrefi denotes som e arbitrary reference state. The local C oulom b repulsion term U  $f_{*}^{y}f_{*}f_{\sharp}^{y}f_{\sharp}$  which is non-zero only for the doubly occupied states can be dropped in the constrained H ilbert space. A fler the elimination of the doubly occupied state we can form ally increase the number of spin components from 2 to arbitrary N.

The H am iltonian in the constrained H ilbert space can be expressed in terms of the slave elds as follows. (the index has been changed to m in anticipation of 1=N expansion)

$$H = \frac{X^{N}}{(k_{m} c)} c_{km}^{y} c_{km} + f X_{m}^{x} s_{m}^{y} s_{m}$$

$$+ \frac{1}{P \frac{1}{N_{lat}}} r \frac{1}{N} X_{km}^{x} (V_{k} s_{m}^{y} b c_{km} + V_{k} c_{km}^{y} b^{y} s_{m})$$

$$+ \frac{1}{2} M 2Q^{2} + \frac{P^{2}}{M} X_{km}^{x} + g_{0}Q (s_{m}^{y} s_{m} h s_{m}^{y} s_{m} i): \qquad (8)$$

The electron-phonon coupling gives rise to the charge uctuation since it couples to the total charge at the impurity site which is either 0 or 1 in the constrained H ilbert space. Note the scaling of the hybridization matrix element  $V_k$  !  $\frac{1}{N}V_k$  in Eq. (8). c is the chemical potential for the conduction electrons. At this point we

pass into the Lagrangian formulation in imaginary time.

$$L = \begin{array}{c} X & h & i \\ C_{km}^{V} & 0 + k & c & 0_{km} \\ & X & h & i \\ + & s_{m}^{V} & 0 + f & s_{m} + b^{V} 0 & b \\ & & T & T & T \\ + & \frac{1}{P \prod_{km}} & r & \frac{1}{N} & (V_{k} s_{m}^{V} b c_{km} + V_{k} c_{km}^{V} b^{V} s_{m} ) \\ & + & \frac{M}{2} & (0 & 2)^{2} + {}^{2} 2^{2} \\ & X & X \\ + & g_{0} Q & s_{m}^{V} s_{m} & h & s_{m}^{V} s_{m} i \\ & + & (S_{m}^{V} s_{m} + b^{V} b & 1); \end{array}$$
(9)

where is a Lagrange multiplier in plementing the constraint Eq. (6). In the 1=N expansion this constraint will be realized through the conserving property of the 1=N expansion.<sup>13</sup> The partition function is given by the following functional integral

$$Z \qquad Z \qquad Z \qquad Z \qquad R \qquad R \qquad R \qquad C = D[b; ] D[s;Q] D[c]e^{-d L}:$$
(10)

The integration over the conduction electrons  $q_{km}$  can be done exactly and it generates a self-energy  $_0$  (i ) for the slave elds.

$${}_{0}(i) = \frac{1}{N_{lat}} \frac{X}{k} \frac{y_{k} f}{i + k}$$

$${}_{Re \ 0} \quad i \ 0 \ sgn();$$

$${}_{0} = N \ (E_{F}) h y_{k} f i_{FS};$$

$$(11)$$

where N (E  $_{\rm F}$ ) is the density of states of the conduction electrons at Ferm i energy and the subscript FS denotes an average over Ferm i surface. The hybridization m atrix elem ent V<sub>k</sub> was assumed to be weakly dependent on momentum near the Ferm i surface of conduction electrons in the second line of Eq. (11). From now on Re $_0$  will be neglected since it is the order of the inverse of energy cuto . A fler the integration over the conduction electrons  $q_{\rm km}$ , the resulting action becomes

S

$$Z \quad h_{X} \qquad i$$

$$= d \quad s_{m}^{y} (\ell + f) s_{m} + b^{y} \ell b$$

$$+ \frac{1}{N} \int_{0}^{z} d d^{0} \int_{0}^{x} (0 - 1) s_{m}^{y} (0) b(0) s_{m}^{y} (0) b^{y} (0)$$

$$+ d \frac{M}{2} (\ell Q)^{2} + 2Q^{2} Z^{0} + d g_{0} Q \quad s_{m}^{y} s_{m} h s_{m}^{y} s_{m} i$$

$$+ d g_{0} Q \quad s_{m}^{y} s_{m} + b^{y} b \quad 1); \qquad (12)$$

where

$$_{0}$$
 (  $^{0}$ ) = T  $^{X}$  e  $^{i}$  (  $^{0}$ )  $_{0}$  (i): (13)

#### B. Read-Newns gauge and Rescalings

The system atic computations of 1=N uctuations can be most clearly achieved in the Read-Newns (RN) gauge:  $1^{13,14,15}$ 

b( ) = R ( )
$$\dot{e}^{i}$$
 ( );  $s_{m}$  ( ) =  $z_{m}$  ( ) $\dot{e}^{i}$  ( ): (14)

Note that the original f-electron operator is invariant under the following gauge transform ation:

$$s_m ! s_m e^{i'}; b! be^{i'}:$$
 (15)

R ( ) 0 is the modulus of complex boson b. Following Colem an  $^{13}$  we write the uctuating Lagrange multiplier as

$$= i_0 + _{sa};$$
 (16)

where  $_{sa}$  is the real part of the saddle point value of the Lagrange multiplier, which is to be determ ined later. In RN gauge, the infrared divergences which plague the expansion in terms of the original elds b; s<sub>h</sub> can be avoided.

The action in RN gauge is expressed as follows:

$$S = \begin{bmatrix} Z & X \\ 0 & x_{m}^{y} & (0 + \gamma_{f}) z_{m} \\ & & \\ + \frac{1}{N} & & \\ 0 & & \\ Z & & \\ + & d \frac{M}{2} & (0 Q)^{2} + & ^{2}Q^{2} \\ & & \\ Z^{0} & X & X \\ + & d g Q & z_{m}^{y} z_{m} & h & z_{m}^{y} z_{m} i \\ & & \\ + & & \\ 0 & & \\ & & \\ + & & \\ 0 & & \\$$

where

$$\gamma_{f} = f + s_{a}; q = 1 = N:$$
 (18)

The integration of phonon Q contributes the following term to the action

$$\frac{g_0^2}{2M} \begin{array}{cccc} Z & Z & & & & \\ & d & d & ^0T & & \frac{e^{i!( & ^0)}}{!^2 + 2} \\ X & & X & & & \\ & & n_{sm} ( ) & n_{sn} ( & ^0); \end{array}$$
(19)

where  $n_{sm} = s_m^y s_m$   $h_m^y s_m$  i. In order for the 1=N expansion to be applicable, each term of the action should be proportional to N. The structure of Eq. (19) suggests that the electron-phonon coupling  $g_0$  should be rescaled as follow s:

$$g_0 = g = \frac{p}{N}$$
: (20)

By the same reason R ( ) should be also rescaled.

$$R() = {p \over N} r()$$
: (21)

The rescaled action becomes

$$S = \overset{Z}{d} \qquad X_{m}^{y} (0 + \gamma_{f}) z_{m}$$

$$S = \overset{0}{d} \overset{m}{z_{m}^{y}} (0 + \gamma_{f}) z_{m}$$

$$+ \overset{0}{d} \overset{M}{d} \overset{M}{2} (0 + \gamma_{f}) z_{m}^{y} () r() z_{m}^{y} () r() z_{m}^{y} () r() r()$$

$$+ \overset{0}{d} \frac{M}{2} (0 + Q)^{2} + \overset{2}{2} Q^{2}$$

$$+ \overset{1}{p} \frac{1}{N} \overset{M}{_{0}} d g Q \qquad z_{m}^{y} z_{m} \qquad M \qquad z_{m}^{y} z_{m} i$$

$$+ \overset{1}{p} \frac{1}{N} \overset{M}{_{0}} d g Q \qquad z_{m}^{y} z_{m} \qquad M \qquad z_{m}^{y} z_{m} i$$

$$+ \overset{0}{d} i (\frac{d}{d} + 0) \qquad X \qquad z_{m}^{y} z_{m}$$

$$+ N \qquad d i (\frac{d}{d} + 0) (r^{2} + q)$$

$$+ N \qquad d \qquad z_{m}^{0} \qquad (22)$$

Now the 1=N expansion can be directly applied to the action Eq. (22).

# III. SADDLE POINT APPROXIMATION

The leading order approximation of the 1=N expansion amounts to the saddle point approximation or equivalently, the mean-eld approximation. The mean-eld theory of in nite-U Anderson model has been studied in great detail in Sec. II of Coleman's paper.<sup>13</sup> Here, we brie y summarize the main results of Ref.<sup>3</sup> for the purpose of the self-contained treatment and the introduction of necessary notations.

We assume that r; take a static value  $r_{sa}$ ;  $_{sa}$  in the saddle point approximation, respectively. In the saddle point approximation the following ucutations with respect to the saddle point value

$$i(\frac{d}{d} + _{0}); r = r _{f_{a}}$$
 (23)

are neglected. We will treat the electron-phonon interaction on an equal footing with the above uctuations, so that the electron-phonon interaction is not included in the saddle point approximation. Now the action appropriate for the saddle point approximation can be expressed as

$$S_{m f} = \begin{bmatrix} Z & X \\ 0 & z_{m}^{y} (\theta + \gamma_{f}) z_{m} \\ & &$$

Next we integrate over  $z_m$  to obtain the saddle point action  $S_{sa}\left(r_{sa}\,;\,_{sa}\right)$  which is

$$e^{S_{sa}(r_{sa}; sa)} = D[z_m] e^{S_{mf}(z; r_{sa}; sa)}: (25)$$

The explicit form of  $S_{sa}$  is given by

$$S_{sa} = N \underset{0}{\overset{d}{\operatorname{sa}}} (r_{sa}^{2} \quad q)$$

$$N \operatorname{Trln} [0 + \sim_{f} + r_{sa}^{2} \quad 0]: \qquad (26)$$

The saddle-point values  $r_{sa}$ ;  $_{sa}$  are determined by minimizing  $S_{sa}$  with respect to them. The minimization with respect to  $_{sa}$  yields

$$r_{sa}^{2} q = T \frac{1}{i f sa + i sgn()};$$
 (27)

where

$$_{0}r_{sa}^{2}$$
: (28)

.

At zero temperature the summation of Eq. (27) can be done in a closed form.

$$r_{sa}^2 \quad q = \frac{h_1}{2} - \frac{1}{2} \tan^{-1} \frac{f + sa}{2}$$
: (29)

Likewise, the minimization with respect to  $r_{sa}^2$  yields

$$_{sa} = T \xrightarrow{X}_{i} \frac{i_{0} \operatorname{sgn}()}{i_{f} \operatorname{sa} + i \operatorname{sgn}()}; \quad (30)$$

At zero tem perature the sum m ation of Eq. (30) can be done in a closed form .

$$_{sa} = \frac{0}{2} \ln \frac{D^2}{^2 + (f + sa)^2}$$
; (31)

where D is an energy cuto which is the order of the bandwidth of conduction electrons. Two real-valued equations Eq. (29) and Eq. (31) can be combined into a single complex-valued equation.

$$\frac{0}{10} \ln \frac{1}{0} + \frac{1}{10} = \frac{1}{10} + \frac{1}{10} = \frac{1}{10}$$
(32)

q	= 0		~ <sub>f</sub> = 0		<sub>к</sub> = 0	
1/2	2:80	10 <sup>3</sup>	2:46	10 <sup>5</sup>	2:80	10 <sup>3</sup>
1/4	1:95	10 <sup>3</sup>	1:99	10 <sup>3</sup>	2 <b>:</b> 79	10 <sup>3</sup>
1/6	1:39	$10^{-3}$	2:41	$10^{-3}$	2:78	$10^{-3}$

TABLE I: The num erical solutions of the saddle point equations Eqs. (29,31). The input parameters are  $D = 65_0$  and  $f = 3.2_0$ . K is dened in Eq. (34).

where

$$= f + sa + i;$$

$$f = f + \frac{0}{2} \ln \frac{D}{0} :$$
(33)

The K ondo lim it is specified by the condition j j = 0, and in this lim it the rst term of the right hand side of Eq. (32) dominates. In the K ondo lim it, the K ondo temperature scale is given by

$$_{\rm K}$$
 j j=  $^{2} + {}^{2}_{\rm f}$  D e  $^{\rm f=0}$ : (34)

This result derived from the saddle point approximation coincides with the one obtaind from the scaling theory of Anderson model by Haldane except for the prefactor.<sup>16,18</sup> A few numerical solutions of Eqs. (29,31) are presented in Table I.From the numerical solutions we nd that in the case of q = 1=2,  $\sim_{f}$ , while for q = 1=4 and 1=6,  $_{f}$ . In all cases  $_{K}$  and are of the same order of magnitude.

#### IV. 1=N FLUCTUATIONS

The 1=N corrections are related to the uctuations with respect to the saddle point conguration. It is convenient to treat the uctuations collectively, so let us de neatwo-component vector X as follows:

$$X = \frac{r}{ir_{sa}};$$
$$= \frac{d}{d} + _{0}; \qquad (35)$$

The 1=N corrections can be computed system atically by expanding the action Eq. (22) with respect to the uc-tuations and by integrating out  $z_m$ . The action Eq. (22)

can be re-expressed as follows.

$$S = S_{X}^{(0)} + S_{z} + S_{ph} + S_{z};$$
(36)

$$S_{X}^{(0)} = \frac{N}{2} d X^{T} (0) X;$$
 (37)

$$S_{z} = i + f i sgn() z_{m}^{y} z_{m}; \quad (38)$$

where

$$^{(0)} = 2 \quad \begin{array}{c} sa & 1 \\ 1 & 0 \end{array} ;$$
 (41)

 $_{\rm m}$  is the source eld necessary for the computation of impurity susceptibilities. The irrelevant constants are om itted in Eq. (36).

Next step is to integrate over  $z_m$  . This step involves  $S_z$  and  $S_z$  of the action Eq. (36). To simplify notations, de ne

$$G_0^{-1}(i) = i + i \operatorname{sgn}()_{f^*}$$
(42)

The integration over  $\boldsymbol{z}_m$  generates

X h  
Trln 
$$G^{(0)}$$
 (  $^{0}$ ) + M ( ;  $^{0}$ ); (43)

where M ( ;  $^{0}$ ) is given by

$$M (; {}^{0}) = {}_{m} + \frac{g}{N}Q + i () ({}^{0}) + {}_{sa} r() + r_{sa} r({}^{0}) + r() r({}^{0})(44)$$

In our approximation we expand the logarithm of Eq. (43) with respect to M ( $;^{0}$ ) up to the second order. This is equivalent to reckoning in the Gaussian<u>p</u> uctuations but not the higher order uctuations in 1= N (see Appendix A).

The relevant part of the expansion is

$$\begin{array}{cccc} X & h & i \\ + & TrG_0M & + \frac{1}{2} & G_0MG_0M & : \\ & & & & \\ \end{array}$$

The details of further calculations are presented in the

appendix B. The e ective action of X ;Q ;  $_{\rm m}$  is given by

$$S_{eff}^{(a)} = \frac{N}{2} X^{T} (i!)^{(1)} X (i!)$$

$$+ \frac{X X^{i}}{P M} (r_{sa}Q) (i!)$$

$$= K^{(1)} (i r_{sa} + m r_{sa}) + K_{r}^{(1)} r (i!)$$

$$+ K^{(1)} (i!) (i r_{sa}) (i!) (m r_{sa}) (i!)$$

$$+ \frac{1}{2} X^{X} X^{(1)} (i!) (m r_{sa})^{2}$$

$$+ K_{r}^{(1)} r (i!) r_{sa} m (i!)$$

$$+ \frac{1}{2} X^{M} X^{i!}$$

$$+ K_{r}^{(1)} r (i!) r_{sa} m (i!)$$

$$+ \frac{1}{2} X^{M} (M !^{2} + M ^{2} + K^{(1)} g^{2} r_{sa}^{2})Q (i!)Q (149);$$

where

<sup>(1)</sup> (i!) = 
$$\begin{array}{c} 2 & _{\text{sa}} + \begin{array}{c} P & _{\text{i=} 0;2;3} \text{K} \stackrel{(i)}{\text{rr}} & 2 + \text{K} \stackrel{(1)}{\text{r}} \\ 2 + \text{K} \stackrel{(1)}{\text{r}} & \text{K} \stackrel{(1)}{\text{r}} \end{array} ; \quad (46)$$

The explicit form s of various polarization functions K can be found in Appendix C.By the saddle point condition Eq. (30),

$$2_{sa} + K_{rr}^{(0)} = 0$$
: (47)

.

.

Then it follows that

<sup>(1)</sup> (i!) = 
$$\begin{array}{c} K_{rr}^{(2)} + K_{rr}^{(3)} & 2 + K_{r}^{(1)} \\ 2 + K_{r}^{(1)} & K^{(1)} \end{array} ; \qquad (48)$$

In fact, only  $\text{ReK}_{rr}^{(2)}$  in the (1,1) element of Eq. (48) contributes to the action due to the symmetry ! \$ !. Now the integration over phonon

$$\exp[S_{eff}^{(b)}] = D[Q] \exp[S_{eff}^{(a)}(X;Q;m)]$$
(49)

contributes the following to  $S_{eff}^{(b)}$ .

7

$$\frac{E_{p}}{2N} r_{sa}^{2} \frac{2}{!^{2} + 2 + K^{(1)}g^{2}r_{sa}^{2}}$$

$$X K^{(1)}r_{sa}(i + m)(i!) + K_{r}^{(1)}r(i!)$$
(50)

where

$$E_{p} = \frac{g^{2}}{M^{2}}$$
 (51)

is the polaron energy. Since we are assuming that the electron-phonon correlation is weak, the relation

$$E_{p} < _{0}$$
 (52)

holds. We will also assume that  $E_{\rm p} > ~_{\rm K}$ , which is more relavant to the real physical systems. The electron-phonon interaction can be traced by following  $E_{\rm p}$ . Let us de ne the following dimensionless function

D (i!) = 
$$\frac{2}{!^2 + 2 + K^{(1)}g^2r_{sa}^2 = M}$$
: (53)

The explicit form of the e ective action  $S^{(b)}_{\rm eff}$  (X ;  $_{\rm m}$  ) is given by

where

$$(i!) = \begin{array}{c} K_{rr} & K_{r} \\ K_{r} & K \end{array};$$

$$K_{rr} = K_{rr}^{(1)} & E_{p}r_{sa}^{2}D(i!)K_{r}^{(1)}I^{2};$$

$$K_{r} = 2 + K_{r}^{(1)} & E_{p}r_{sa}^{2}D(i!)K_{r}^{(1)}K^{(1)};$$

$$K = K^{(1)} & 1 & E_{p}D(i!)r_{sa}^{2}K^{(1)}:$$
(55)

F inally the integration over X

$$\exp[S_{eff}^{(c)}(m)] = D[X] \exp[S_{eff}^{(b)}(X;m)]$$
(56)

7.

yields the e ective action of m .

$$S_{eff}^{(c)} = \frac{1}{2} X X_{m (i)} (i!) r_{sa (m)}^{2} (i!)_{m} (i!)_{m}$$

V. THE SPIN AND THE CHARGE SUSCEPTIBILITIES OF IM PURITY

The spin susceptibility of impurity is de ned by

$$s \begin{pmatrix} 0 \\ z \end{pmatrix} = \lim_{X} z \begin{pmatrix} 0 \\ z \end{pmatrix} M_{z} \begin{pmatrix} 0 \\ z \end{pmatrix} i;$$
 (58)  
$$M_{z} = \max_{x}^{y} s_{m} = \max_{x}^{y} z_{m};$$
 (59)

$$A_{z} = m s_{m}^{y} s_{m} = m z_{m}^{y} z_{m};$$
 (59)

where the sum over m runs from N = 2 to N = 2. The charge susceptibility is defined by

$$_{c}$$
 ( <sup>0</sup>) = h  $\hat{n}_{f}$  ( )  $\hat{r}_{f}$  ( <sup>0</sup>)  $\dot{i}_{j}$  (60)

where

$$\hat{\mathbf{n}}_{\mathrm{f}} = \begin{array}{ccc} X & X & X \\ \mathbf{s}_{\mathrm{m}}^{\mathrm{y}} \mathbf{s}_{\mathrm{m}} & \mathbf{h} & \mathbf{s}_{\mathrm{m}}^{\mathrm{y}} \mathbf{s}_{\mathrm{m}} \mathbf{i} \\ & = \begin{array}{ccc} X^{\mathrm{m}} & X^{\mathrm{m}} & X \\ \mathbf{z}_{\mathrm{m}}^{\mathrm{y}} \mathbf{z}_{\mathrm{m}} & \mathbf{h} & \mathbf{z}_{\mathrm{m}}^{\mathrm{y}} \mathbf{z}_{\mathrm{m}} \mathbf{i} \\ & & & & & \\ \end{array}$$
(61)

The spin and charge susceptibilites can be computed from

$$m_{n}(; )^{0} = \frac{2 \ln Z}{m() n()} :$$
(62)

Here the partition function Z is understood to be a functional of  $_{\rm m}$  only, namely all other elds should be integrated out. In our approximation,

$$Z = D[_{m}] \exp[S_{eff}^{(c)}(_{m})];$$
 (63)

where  $S_{eff}^{(c)}$  (  $_m$  ) is given by Eq. (57).  $_{mn}$  ( ; <sup>0</sup>) in frequency space is given by

$$m_n (; ^0) = T \begin{bmatrix} X \\ m_n (i!) e^{i!} ( ^{0}) \end{bmatrix}$$
 (64)

Then it follows that

$$c_{c}(i!) = X \\ m_{n}(i!); \\ s_{s}(i!) = m_{n} m_{n}(i!);$$

$$c_{m,n}^{m,n} (i!);$$

$$c_{m,n}^{m,n} (i!):$$

$$c_{m,n}^{m,n} (i!):$$

$$c_{m,n}^{m,n} (i!):$$

$$c_{m,n}^{m,n} (i!):$$

$$c_{m,n}^{m,n} (i!):$$

$$c_{m,n}^{m,n} (i!):$$

From Eq.(62) we nd

$$mn = mn r_{sa}^{2} K^{(1)} (i!)$$

$$+ \frac{r_{sa}^{2}}{N} 1 E_{p} D (i!) r_{sa}^{2} K^{(1)}^{2}$$

$$K_{r}^{(1)}; K^{(1)} \frac{1}{N} K_{r}^{(1)}$$

$$+ \frac{r_{sa}^{4}}{N} E_{p} D (i!) K^{(1)} (i!)^{i_{2}}:$$
(66)

From Eq. (66) the spin susceptibility is readily obtained

$$s(i!) = m^{2} \sim_{s} (i!);$$

$$m^{m} \sim_{s} (i!) = f_{sa}^{2} K^{(1)} (i!): (67)$$

In our approximation scheme the spin susceptibility is not renormalized by the electron-phonon interaction. C learly this is an artifact of the approximation of the saddle point and the Gaussian uctuation. If the uctuations beyond the Gaussian uctuations (higher order in 1 = N)

are considered the spin susceptibility is expected to be renorm alized by the electron-phonon. How ever, the corrections due to higher order uctuations will be rather sm all. It is illum inating to compare this result with that of num erical renorm alization group studies. Hew son and M eyer have com puted the im aginary part of the retarded spin susceptibility for the symmetric and nite-U AH model (see the Fig. 13 of Ref. 6. Compare two cases with = 0.0 and = 0.02). Their result shows that the electron-phonon interaction does not in uence the qualitative behavior of the spin susceptibility except for the decrease of the peak height at very low energy around the K ondo tem perature scale. For our param eter regim e where the electron correlation is farm ore dom inant over the electron-phonon interaction, the decrease of the peak height would be hardly noticeable.

The charge susceptibility  $_{c}$  (i!) is given by

$$c (i!) = N = r_{sa}^{2} 1 E_{p}D (i!)r_{sa}^{2}K^{(1)}^{2}$$

$$K_{r}^{(1)}; K^{(1)} K_{r}^{(1)} K^{(1)}^{1} K_{r}^{(1)}$$

$$r_{sa}^{2}K^{(1)} (i!) 1 E_{p}D (i!)r_{sa}^{2}K^{(1)}$$

$$c (i!): (68)$$

The charge susceptibility is indeed renormalized by the electron-phonon interaction in a very complicated way. This complicated expression can be recast in a more transparent form in the following way. First note that the charge susceptibility in the absence of the electronphonon interaction is given by

$$\sim_{c}^{(0)} = r_{sa}^{2} K_{r}^{(1)}; K^{(1)}_{r}; K^{(1)}_{r} K^{(1)}_{r} K^{(1)}_{r}; K^{(1)}_{r} K^{(1)}_{r}; (69)$$

This result can be obtaind from Eq. (68) by putting  $E_p = 0$  everywhere and was derived by Coleman.<sup>13</sup> Explicit calculation shows that

$$\sim_{c}^{(0)}$$
 (i!) =  $4r_{sa}^{2} \frac{K^{(1)}}{K_{rr}^{(1)}K^{(1)}} \frac{K^{(1)}}{(K_{r}^{(1)}+2)^{2}}$  (70)

For the subsequent analyses it is helpful to exam ine the susceptibilities in the absence of phonons in more detail. The susceptibilities at zero frequency in the absence of phonons are given by

$$\sim_{s}^{(0)} (i! = 0) = \frac{1}{\frac{2}{K}};$$
  
$$\sim_{c}^{(0)} (i! = 0) = \frac{1}{(0 + \frac{2}{K})^{2} + (0)^{2}}; \quad (71)$$

In the K ondo regime, the relation  $_0$   $^2 + \gamma_f^2$  holds, so that we have

$$\sim_{\rm C}^{(0)} (! = 0) \quad -\frac{2}{0}$$
: (72)



FIG.1: The real and in aginary part of the retarded charge susceptibility in real frequency in the absence of electronphonon interaction  $\sim_c^{R,(0)}$  (i! ! ! + i ). The dashed line and the solid line indicates the real part and the in aginary part, respectively. Note that the frequency is in the logarithmic scale, and the y-axis is in the absolute scale. The input parameters are identical with those of Table I. The value of q is 1/2.

The ratio of the charge and spin susceptibility at zero frequency is then given by

$$\sim_{c}^{(0)}$$
 (i! = 0)= $\sim_{s}^{(0)}$  (i! = 0)  $\frac{K}{0}^{2}$  1: (73)

In fact, over most of the frequency range of interest, the absolute m agnitude of spin susceptibility is far greater than that of the charge susceptibility. This is because the charge uctuations are severely suppressed by the very strong local C oulom b repulsion in the low temperature K ondo regime, while the spin uctuations (spin ips) are the dom inant processes there.

We also note that  $\sim_c^{(0)}$  (i!) is related to the propagator h r(i!) r(i!)<sup>(1)</sup> in the absence of phonon in the following way

h r(i!) r( i!)<sup>(p)</sup> = 
$$\frac{1}{N} \frac{1}{4r_{sa}^2} \sim_c^{(0)}$$
 (i!); (74)

which can be shown by inverting the matrix  $\ ^{(1)}$  (i!). This implies that higher order corrections stem m ing from the bose uctuations are suppressed in the limit of large N .

U sing the above results on the susceptibilities in the absence of phonon and expanding the matrix  $^{1}$  up to the second order of g, the result Eq. (68) in the presence of phonon can be expressed in a more transparent form :

$$\begin{array}{c} h & i \\ c(i!) & \sim_{c}^{(0)}(i!) & 1 + E_{p}D(i!) \sim_{c}^{(0)}(i!); \end{array}$$
(75)

where D (i!) is de ned by Eq. 53). Using the previous results we nd

$$E_{p}D(i!) \sim_{C}^{(0)}(i!)$$
 1: (76)



FIG.2: The imaginary parts of the retarded charge susceptibility and spin susceptibility in the absence of electron-phonon interaction. The charge susceptibility has been multiplied by a factor of 25,000 to make comparison easier. The input parameters are identical with those of Table I.q = 1=2.

The structure of Eq. (75) clearly prompts us to write

$$\sim_{c} (i!) \quad \frac{\sim_{c}^{(0)} (i!)}{1 \quad E_{p} D (i!) \sim_{c}^{(0)} (i!)} :$$
(77)

The imaginary part of the retarded charge susceptibility  $\mathbb{E}q. (75)$ ] in real frequency can be expressed as

$$\lim_{c} \sim_{c}^{R} (!) \qquad \lim_{c} \sim_{c}^{(0);R} (!)$$

$$1 + E_{p} Re \mathbb{D}^{R} (!) Re [\sim_{c}^{R;(0)} (!)] ; (78)$$

where only the leading contribution is exhibited. As depicted in Fig. 1, the variations of  $Re[\sim_c^{R;(0)}(!)]$  is almost negligible for all frequency region below the frequency of the order of  $j_f$  j. Therefore, the major frequency dependence of the electron-phonon correction to the charge susceptibility originates from  $Re\mathbb{D}^R$  (!):

$$\operatorname{Re}\mathbb{D}^{\mathbb{R}}(!)] \xrightarrow{2}{!^{2}+2};$$
 (79)

where the singularity at ! = is cut-o by the in aginary part of K<sup>(1)</sup> but this is irrelevant in our discussion. In view of Eq. (79) a qualitative change near the phonon frequency is expected. More speci cially, one can expect that the in aginary part of the charge susceptibility is to be enhanced at frequency slightly low er than the phonon frequency while it is expected to be reduced at frequency slightly higher than the phonon frequency. This expectation is in good agreem ent with the results of NRG studies by Hew son and M eyer (see the left panel of F ig. 13 in R ef. 6 and com pare two cases of = 0.0 and = 0.02).

The charge susceptibility at zero frequency in the presence of phonon can be expressed

$$\sim_{c} (i! = 0) \quad \frac{2}{0} \quad 1 + \frac{E_{p}}{0} :$$
 (80)

For the case of q = 1=2 the relation K holds, and the result Eq. (80) can be interpreted from the view point



FIG.3: The real parts of the retarded charge susceptibility and spin susceptibility in the absence of electron-phonon interaction. The charge susceptibility has been multiplied by a factor of 10,000 to make comparison easier. The input param eters are identical with those of Table I. q = 1=2.

of the renorm alization of K ondo tem perature by electronphonon interaction.

$$T_{K} = T_{K}^{(0)} + \frac{E_{p}}{\frac{2}{0}}$$
; (81)

where  $T_{K}^{(0)} = K$  is the K ondo tem perature in the absence of phonons. The Eq. (81) indicates that the electron-phonon interaction increases the K ondo tem perature, which is consistent with the recent results found by NRG method.<sup>6,7</sup>. Since  $E_{p} < 0$  and 0 the amount of increase is rather small. This smallness of renormalization is again due to the suppressed charge uctuations. With C oulomb repulsion xed to be in -

nite from the outset, the charge uctuation is controlled by the  $_{\rm f}$ . As the in purity level goes down deeper into the Ferm isea of conduction electron, evidently the charge uctuation is reduced. As can be seen in Eq. §4), decreases exponentially with the decreasing  $_{\rm f}$  (in the sense of becom ing m ore negative).

#### VI. PHONON PROPAGATOR

The phonon propagator can be obtained from the action Eq. (45) by setting the source eld  $_{\rm m}$  to zero and then by integrating over the bose  $\,$  uctuations X and the ferm ions  $z_{\rm m}$ .

$$D_{ph}(i!) = M!^{2} + M^{2} g^{2} c^{(0)}_{c}(i!)$$
(82)

The physics of K ondo xed point is built in  $c_c^{(0)}$  (i!). If the bose uctuations X were not taken into account, the phonon propagator would be

<sup>h</sup>  
M!<sup>2</sup> + M<sup>2</sup> 
$$g^2 \sim_s^{(0)}$$
 (i!) : (83)

This can be seen from Eq. (45) by setting the bose uctuation X and the source eld  $_{m}$  to zero, and then by

integrating over  $z_m$ . As discussed in Sec.V and can be seen F ig. 2 and F ig. 3 the charge and spin susceptibility of in purity behave essentially di erently from each other. F irst of all, the absolute m agnitude of the spin susceptibility by the order of magnitudes. Second the frequency dependences are also di erent from each other. T he in aginary part of the spin susceptibility Im  $\sim_s^{R;(0)}$  (!) has a sharp peak at ! K, while the imaginary part of the charge susceptibility Im  $\sim_c^{R;(0)}$  (!) has a rather broad peak at frequency higher than K. Im  $\sim_c^{R;(0)}$  (!) also has a peak at high frequency order of frequency order of frequency order of frequency order of frequency higher than K.

If the bose uctuations were not considered, then based on Eq. (83) one would anticipate rather substantial renormalization even for the relatively small values of g. This is in stark contrast with the results by NRG<sup>6,7</sup> which show rather small renorm alization. To make arguments more concrete let us compare last two terms in the bracket of Eq. (83) at zero frequency. Using the result Eq. (71) we obtain

$$\frac{g^2 \sim_s^{(0)} (i! = 0)}{M^{2}} \quad \frac{E_p}{K} > 1$$
 (84)

for physically relevant cases.

However, regarding the result Eq. (82) for which the bose uctuations taken into account, the ratio becomes

$$\frac{g^2 \sim_c^{(0)} (i! = 0)}{M^2} = \frac{E_{p-K}}{\frac{2}{0}} = 1;$$
(85)

which agrees with the results by NRG. Thus, unless the electron-phonon interaction is extrem ely strong, the selfenergy correction to the phonon propagator coming from the electronic sector is small. But if the electron-phonon interaction becomes so strong that the ratio Eq. (85) becomes order of unity, the saddle point we have started with won't be valid any more and new saddle points will emerge. The results by NRG studies indeed demonstrate that new features emerge in the strong coupling regime of electron-phonon interaction. Unfortunately our approxim ation scheme does not apply in that regime. In any case we conclude that to obtain the physically correct result it is absolutely essential to include the 1=N bose uctuations X.

The form of the phonon propagator Eq. (82) suggests that the phonon frequency softens. The renormalized phonon frequency is given by

ren 
$$1 - \frac{E_p}{2} = \frac{E_p}{0}$$
 : (86)

The result Eq. (86) can be compared with that derived in the weak (electron-electron and electron-phonon) coupling random phase approximation type perturbative calculations:<sup>7</sup>

ren 1 
$$\frac{E_p}{0}$$
 : (87)

The result Eq. (86) should be also compared with that derived in the sem iclassical approximation for the large but nite-U and symmetric AH model.<sup>19</sup>

ren 1 
$$\frac{E_{p}}{U^2}$$
: (88)

The results Eqs. (86,88) indicate that the strong C oulom b repulsion suppresses the softening of phonon frequency but the detailed form of the softening depends crucially on the details of H am iltonian such as the sym m etric or asym m etric nature of charge uctuations of Anderson m odel.

# VII. SUM MARY AND CONCLUDING REMARKS

We have studied the AH model with the in nite localCoulomb repulsion. The limit of the in nite local Coulom b repulsion elim inates the doubly occupied states in the Hilbert space of in purity. The slave boson method is very e ective in treating the problem s with the constrained H ilbert space, where the strong correlation is actually built in the constraint itself. In general the slave boson method is more reliable in the low temperature regime where the thermal uctuations are small. The 1=N expansion scheme is employed to control approxim ations system atically and it is found that the electronphonon interaction can be naturally t into the scheme. Remarkably the nonperturbative physics of the low tem perature K ondo xed point is captured in the leading approximation. We have used the saddle point approxin ation supplemented with the Gaussian uctuations. In fact, the Gaussian uctuations play a very crucial role in determ ining the physical properties of impurity and phonon. The spin susceptibility is not renormalized up to this approximation. The K ondo tem perature is found to increase by the elctron-phonon interaction but by a rather sm all am ount. The same is true of the charge susceptibility and phonon propagator. This is because the quantum uctuations of phonon which couple to the charge uctuations of the impurity electron are suppressed by the very strong local electron correlation. But the interplay between the strong electron correlation and the electron-phonon interaction is clearly displayed.

We could also have calculated the electron spectral function but all the important features such as the increase of the K ondo temperatures and the pronounced phonon e ect near the phonon freqency are essentially identical with those of the charge susceptibility.

The AH m odel can be naturally generalized to the im purity m odels with the orbital degrees of freedom. As a m atter of fact, this is m uch m ore realistic m odel than the AH m odel since the electron correlation e ects are m ore prom inent in the d and f electron systems where the orbital degrees of freedom are active. For these cases the sim ple H olstein phonon should be also generalized to incorporate Jahn-Teller type phonons.<sup>1</sup> Slave boson approach can be extended to the orbitally active cases, and currently the progresses in this direction are being m ade by the authors.

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### APPENDIX A: ILLUSTRATION OF THE BASIC IDEA OF 1=N EXPANSION

Let us brie y illustrate the basic idea of 1=N expansion in the case of one-dimensional integral. Consider an integralI of the following form de ned on a certain domain D:

$$I = e^{N g(x)}; N 1: (A1)$$

If a m inimum of  $g\left(x\right)$  is attained at  $x_{0}$  2 D , then the function can be expanded

$$g(\mathbf{x}) \quad g(\mathbf{x}_{0}) + \frac{1}{2}g^{(2)}(\mathbf{x}_{0})(\mathbf{x} - \mathbf{x}_{0})^{2} + \frac{X}{n-3} \frac{g^{(n)}(\mathbf{x}_{0})}{n!}(\mathbf{x} - \mathbf{x}_{0})^{n};$$
(A 2)

where  $g^{(n)}$  denotes the n-th derivative and  $g^{(2)}(x_0) > 0$ . Dening a rescaled variable z

$$z = \frac{p}{N} \frac{1}{p(2)(x_0)} (x - x_0)$$
 (A 3)

the integral I can be approxim ated by

$$I = e^{N g(x_0)} \ln [N g^{(2)}(x_0)] = 2 \qquad dz e^{z^2 = 2 c_1 z^3 = \frac{p}{N} + \frac{p}{N}} e^{N g(x_0)} \ln [N g^{(2)}(x_0)] = 2 \qquad p = \frac{p}{2} + \frac{const.}{p} + (A 4)$$

The integration over z can be done system atically as a power series expansion in  $1 = \frac{N}{N}$ . In this paper we ignore the corrections of order  $1 = \frac{N}{N}$  and higher in the bracket of Eq. (A 4), but they can be computed in a controllable way if desired.

# APPENDIX B:DETAILS OF THE CALCULATIONS OF 1=N CORRECTIONS

First let us specify the measure for the functional integral in the RN gauge. This is discussed in Sec. III B of Ref. 13, and here we give an equivalent but technically slightly di erent treatment. The measure of boson functional integral is given by

$$D[r;] = \frac{Y}{2} \frac{dr^{2}()}{2}:$$
 (B1)

The ferm ion measure is invariant under the RN gauge transform ation.

$$D[s;s^{y}] = D[z;z^{y}]:$$
 (B2)

The angular variable in the sector with the winding number m can be expanded  $^{13}$ 

$$(m)() = \frac{1}{p-1} X_{n} e^{i_{n}} + 2 m -;$$
 (B3)

where  $_{n}$  is the bosonic M atsubara frequency given by  $_{n} = 2 \, n=$ . This expansion automatically satisfies esthe winding number condition without further conditions im – posed on the coefficients  $_{n}$ . The zero mode term  $_{0}$  should be factored out since our action does not depend on it. For the variation which involves only the zero mode we have d  $_{0}^{(m)} = 1 = {p - d}_{0}$ . Factoring out  ${d}_{0}^{(m)}$  we obtain

$$D[] = \sum_{m = n \in 0}^{X} \frac{p - Y}{2} \frac{d_{n}}{2} :$$
 (B4)

O noe the zero m ode term is factored out both () and d ()=d are characterized by the same set of coe cients f  $_{n\,6\,0}g$  and an integer m . Explicitly

$$\frac{d}{d} = 2 m = + \frac{1}{p} \sum_{n \in 0}^{X} (i_n)_n e^{i_n} :$$

From the above expression we nd that the constant part of  $\frac{d}{d}$  is constrained to take a value which is an integral multiple of 2 = . However, as can be seen in Eq. (22)  $\frac{d}{d}$  always appears in combination with  $_0$ . Since  $_0$  is a part of Lagrange multiplier in plementing delta function constraint it is non-compact, in other words, it can take an arbitrary realvalue. Now the explicit sum mation over the winding number is unnecessary and we need only to consider a bose eld

$$=\frac{d}{d}+_{0};$$
 (B5)

which has an ordinary mode expasion without any constraint. E ectively we can replace D [] with D [].

If the uctuations beyond the Gaussian uctuation of the order 1=N can be ignored, namely the corrections of order 1=N  $^{3=2}$  and higher can be ignored, the functional measure for the r integration can be approximated by

$$dr^{2}() = 2r()dr()$$
 2rd r(): (B6)

The higher order corrections can be important at high tem perature or energy. We also note that due to the periodicity r(0) = r(),  $_0 d r \frac{e^{r}}{e} = 0$ . Thus, at low energy the measure for the boson functional integral becomes

$$D[r; ] r_{sa}dr()d():$$
 (B7)

This is of a simple Cartesian product form, so that we don't have to dealwith the interactions which m ight be generated by the nontrivial Jacobians of functional integralm easure.

Now we turn to the details of the calculation of Eq. (43). Let us rewrite Eq. (43) as follows:

$$S = X Trh[(G_0^{1})(1 G_0M)]$$

$$= X^{m} Trh[G_0^{1}] Trh(1 G_0M)$$

$$= Trh[G_0^{1}] Trh(1 G_0M)$$

$$= Trh[G_0^{1}] + TrG_0M$$

$$+ \frac{1}{2} X^{m} TrG_0MG_0M : (B8)$$

In the absence of the source eld  $_{\rm m}$  the sum over m would just give an overall factor N. The set term of the last line of Eq. (B8) is relevant for the mean-eld approximation. The second term  $_{\rm m}$  Trh [G\_0M] contains a few parts. Among them gQ part is cancelled by the very de nition of electron-phonon coupling, and the part linear in r is cancelled by the saddle point condition. The remaining nontrivial part is given by

$$X \qquad X \qquad X \qquad Z 
Trln G_0 M ! \qquad d_m G_0 
+ \frac{N}{2} X \qquad h \qquad i 
K \qquad rr + K \qquad rr \qquad r(i!) r(i!); (B9) 
K \qquad rr \qquad r(i!); (B9) 
K \qquad rr \qquad r(i!) r(i!); r(i$$

where K  $_{\rm rr}^{(0)}$  and K  $_{\rm rr}^{(2)}$  are given by

$$K_{rr}^{(0)} = 2T \qquad G_{0}(i)_{0}(i); \qquad (B10)$$

$$K_{rr}^{(2)}(i!) = 2T \quad G_0(i)_0(i+i!)_0(i)$$

The third term  $\frac{1}{2}^{P}_{m}$  Trln[G<sub>0</sub>MG<sub>0</sub>M] can be reexpressed as follows:

$$\frac{1}{2} \sum_{m}^{X} \operatorname{Tr} \ln [G_{0}M G_{0}M] = \frac{N}{2} \sum_{i!}^{X} K_{rr}^{(3)} r(i!) r(i!)$$

$$\frac{1}{2} \sum_{m i!}^{X} K^{(1)} r_{sa}^{2} (i + \frac{g}{pN}Q + m)(i!)$$

$$(i + \frac{g}{N}Q + m)(i!)$$

$$+ \frac{1}{2} \sum_{m i!}^{X} 2K_{r}^{(1)} r(i!) r_{sa} (i + \frac{g}{N}Q + m)(ki!)$$

where

$$K_{rr}^{(3)}(i!) = r_{sa}^{2}T X_{G_{0}}(i)G_{0}(i + i!)$$

$${}_{i}^{(1)}(i!) = \frac{1}{r_{sa}^{2}}T G_{0}(i)G_{0}(i + i!)^{2};$$

$$K_{r}^{(1)}(i!) = \frac{1}{r_{sa}^{2}}T G_{0}(i)G_{0}(i + i!);$$

$$K_{r}^{(1)} = T G_{0}(i)G_{0}(i + i!)$$

$${}_{i}^{(1)}(i!) = \frac{1}{r_{sa}^{2}}T G_{0}(i + i!);$$

$$K_{r}^{(1)}(i!) = \frac{1}{r_{sa}^{2}}T G_{0}(i + i!);$$

$$G_{r}^{(1)}(i!) = \frac{1}{r_{sa}^{2}}T G_{0}(i + i!);$$

$$K_{r}^{(1)}(i!) = \frac{1}{r_{sa}^{2}}T G_{0}(i + i!);$$

$$G_{r}^{(1)}(i!) = \frac{1}{r_{sa}^{2}}T G_{0}(i + i!);$$

# APPEND IX C:THE EXPLICIT FORM SOF THE POLAR IZATION FUNCTIONS K <sup>(i)</sup> (i! ) AT ZERO TEM PERATURE

The polarization functions K (i!) have been calculated in Appendix A of Ref. 13 in terms of the digam m a function at nite tem perature. We will instead calculate the polarization functions at zero tem perature in a closed form. The integrations are completely elementary, and only the results and the low frequency asymptotic behaviors will be displayed. First we note that only the real part of K  $_{\rm rr}^{(2)}$  (i!) which is an even function of frequency contributes to the elective action.

$$\operatorname{ReK}_{rr}^{(2)}(i!) = -\frac{0}{\ln} \ln \frac{h(j!j+1)^2 + \gamma_{f}^2}{\frac{2}{2} + \gamma_{f}^2} : \quad (C1)$$

$$K_{rr}^{(3)}(i!) = \frac{2_{0}}{j!j} \ln^{h} \frac{(j!j+)^{2} + \gamma_{f}^{2}}{2 + \gamma_{f}^{2}}^{i} : \qquad (C2)$$

The sum of the above two gives

$$K_{rr}^{(1)}(j!) = ReK_{rr}^{(2)} + K_{rr}^{(3)}$$
  
=  $+ \frac{0}{-\frac{j!}{j!} \frac{j!}{j!}} \frac{j!}{j!} \frac{j!}{j!} \frac{j!}{j!} \frac{j!}{j!} \frac{j(j!}{j!} \frac{j!}{j!} \frac{j!}{j!}$ 

And the rest are given by

$$K_{r}^{(1)}(j!) = \frac{2_{0}}{j!j} \tan^{1} \frac{\gamma_{f} j! j}{2 + \gamma_{f}^{2} + j! j}$$
 (C4)

#

$$K^{(1)}(j!) = \frac{0}{j!j(j!j+2)} \ln^{h} 1 + \frac{j!j(2+j!j)}{\frac{2}{K}} \cdot \frac{j!j}{(C5)}$$

The low (im aginary) frequency asymptotic behaviors are given by

$$K_{r}^{(1)}(i!) = \frac{4_{0}}{\frac{2}{K}} h_{r}^{2} + \frac{j! j_{f}^{2} i}{\frac{4}{K}}$$
(C 6)

$$K_{r}^{(1)}$$
 (i!)  $\frac{2}{2} - \frac{1}{2} - \frac{1}{$ 

K<sup>(1)</sup>(i!) 
$$\frac{1}{r_{sa}^2} - \frac{1}{r_{fa}^2} + \frac{1}{r_{sa}^2} \frac{j! j^2}{(r_{sa}^2 + r_{fa}^2)^2}$$
: (C8)

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